



DST3906DJ

DUAL 40V PNP SURFACE MOUNT TRANSISTOR

Features

- V_{CEO} = -40V
- I_C = -200mA
- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Ultra Small Package

Mechanical Data

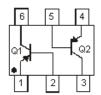
Case: SOT963

- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.0027 grams (Approximate)

SOT963







Device Schematic

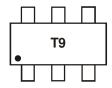
Ordering Information (Note 4)

Part Number	Packaging	Shipping
DST3906DJ-7	SOT963	10.000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



T9 = Product Type Marking Code



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous (Note 5)	Ic	-200	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. Device mounted on FR-4 PCB with minimum recommended pad layout. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:



Thermal Characteristics and Derating Information

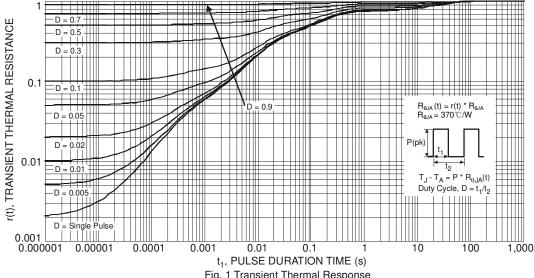
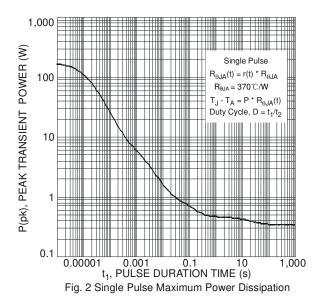


Fig. 1 Transient Thermal Response



0.4 P_D, POWER DISSIPATION (W) 1.0 2.0 3.0 1.0 60 80 100 120 T_A , AMBIENT TEMPERATURE (°C)

Fig. 3 Power Dissipation vs. Ambient Temperature



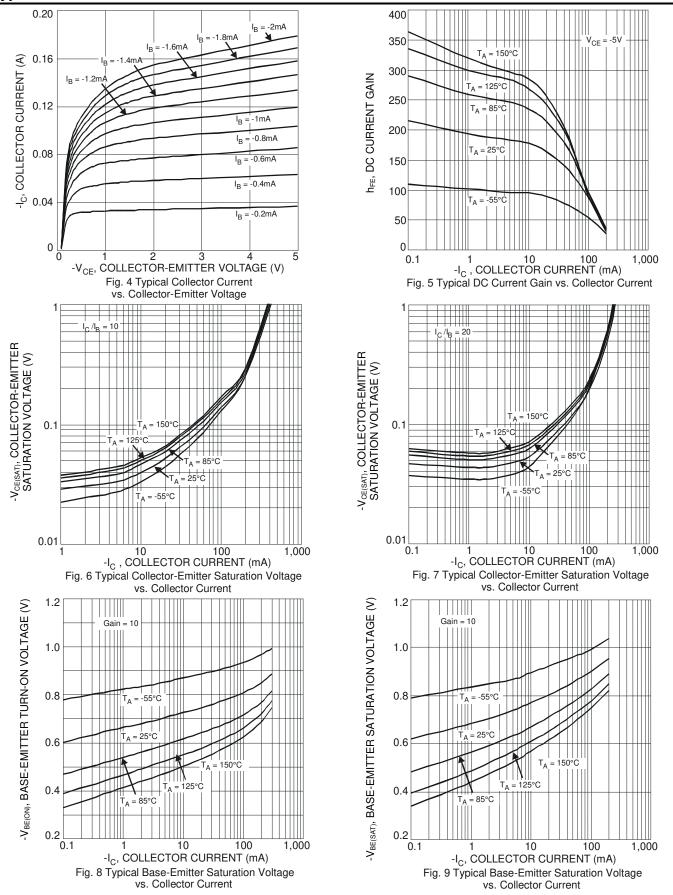
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40	_	V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 7)	$V_{(BR)CEO}$	-40		V	$I_C = -1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-6		V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I _{CEX}	_	-50	nA	$V_{CE} = -30V$, $V_{EB(OFF)} = -3V$
Collector Cuton Current	I _{CBO}	_	-50	nA	$V_{CB} = -30V, I_{E} = 0$
Base Cutoff Current	I_{BL}	_	-50	nA	$V_{CE} = -30V$, $V_{EB(OFF)} = -3V$
ON CHARACTERISTICS (Note 7)					
		60	_		$I_C = -100 \mu A, V_{CE} = -1 V$
		80	_		$I_C = -1.0 \text{mA}, V_{CE} = -1 \text{V}$
DC Current Gain	h_{FE}	100	300	_	$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
		60	_		$I_C = -50 \text{mA}, V_{CE} = -1 \text{V}$
		30	_		$I_C = -100 \text{mA}, V_{CE} = -1 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.25	V	$I_C = -10mA$, $I_B = -1mA$
Oollector-Emitter Saturation Voltage			-0.40	V	$I_C = -50$ mA, $I_B = -5$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.65	-0.85	V	$I_C = -10mA$, $I_B = -1mA$
, and the second		_	-0.95		$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{OBO}		4.5	pF	$V_{CB} = -5V$, $f = 1MHz$, $I_E = 0$
Input Capacitance	CIBO	_	10	pF	$V_{EB} = -0.5V$, $f = 1MHz$, $I_{C} = 0$
Input Impedance	h _{ie}	2	12	kΩ	
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	$V_{CE} = -10V, I_{C} = -1mA,$
Small Signal Current Gain	h _{fe}	100	400	_	f = 1kHz
Output Admittance	h _{oe}	3	60	μS	
Current Gain-Bandwidth Product	f _T	300	1	MHz	$V_{CE} = -20V, I_{C} = -10mA,$ f = 100MHz
SWITCHING CHARACTERISTICS					
Delay Time	t _D		35	ns	$V_{CC} = -3V, I_{C} = -10mA,$
Rise Time	t _R	_	35	ns	$I_{B1} = -1mA$
Storage Time	ts	_	225	ns	$V_{CC} = -3V, I_{C} = -10mA,$
Fall Time	t _F		75	ns	$I_{B2} = 1mA$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

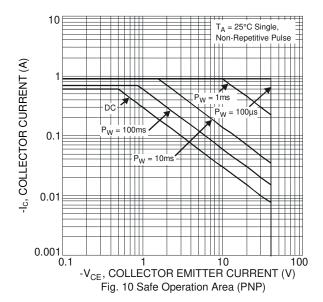


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Typical Electrical Characteristics (Cont. @TA = +25°C, unless otherwise specified.)

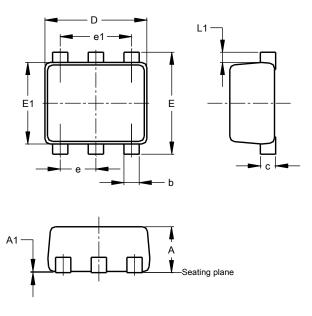




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT963

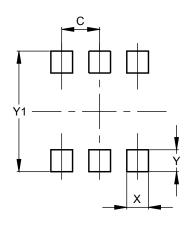


SOT963					
Dim	Dim Min		Тур		
Α	0.40	0.50	0.45		
A1	0.00	0.05			
b	0.10	0.20	0.15		
С	0.120	0.180	0.150		
D	0.95	1.05	1.00		
Е	0.95	1.05	1.00		
E1	0.75	0.85	0.80		
е			0.35		
e1			0.70		
L1	0.05	0.15	0.10		
All Dimensions in mm					

Suggest Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT963



Dimensions	Value (in mm)		
С	0.350		
Х	0.200		
Υ	0.200		
Y1	1.100		

Note:

The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary depending on application. These dimensions may be modified based on user equipment capability or fabrication criteria. A more robust pattern may be desired for wave soldering and is calculated by adding 0.2mm to the 'Z' dimension. For further information, please reference document IPC-7351A, Naming Convention for Standard SMT Land Patterns, and for International grid details, please see document IEC, Publication 97.



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